2.5V Drive Nch MOS FET

RJK005N03

Structure

Silicon N-channel MOS FET

● Features

- 1) Low On-resistance.
- 2) Low voltage drive (2.5V drive).

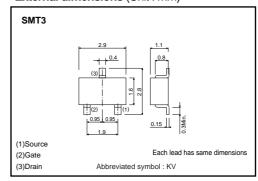
Applications

Switching

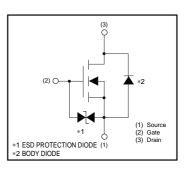
●Packaging specifications and hFE

	Package	Taping
Type	Code	T146
	Basic ordering unit (pieces)	3000
RJK005N03	0	

●External dimensions (Unit : mm)



•Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	30	V
Gate-source voltage		Vgss	±12	V
Drain current	Continuous	ID	±500	mA
	Pulsed	IDP *1	±2.0	Α
Source current	Continuous	Is	200	mA
(Body Diode)	Pulsed	Isp *1	800	mA
Total power dissipation		Pp *2	200	mW
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	625	°C/W

^{*} Each terminal mounted on a recommended land

^{*1} Pw≤10µs, Duty cycle≤1% *2 Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μΑ	Vgs=±12V, Vps=0V
Drain-source breakdown voltage	V _{(BR) DSS}	30	_	_	V	I _D = 1mA, V _{GS} =0V
Zero gate voltage drain current	IDSS	-	_	1	μΑ	V _{DS} = 30V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	8.0	_	1.5	V	V _{DS} = 10V, I _D = 1mA
		-	400	580	mΩ	I _D = 500mA, V _{GS} = 4.5V
Static drain-source on-state resistance	R _{DS (on)} *	-	420	600	mΩ	I _D = 500mA, V _{GS} = 4V
resistance		-	650	940	mΩ	I _D = 500mA, V _{GS} = 2.5V
Forward transfer admittance	Y _{fs} *	0.5	_	_	S	V _{DS} = 10V, I _D = 500mA
Input capacitance	Ciss	-	60	_	pF	V _{DS} = 10V
Output capacitance	Coss	_	24	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	12	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	9	_	ns	V _{DD} ≒ 15V
Rise time	tr *	_	11	_	ns	ID= 250mA
Turn-off delay time	td (off) *	_	16	_	ns	V _{GS} = 4V R _L =60Ω
Fall time	t _f *	-	31	_	ns	R _G =10Ω
Total gate charge	Qg *	_	2.0	4.0	nC	V _{DD} ≒24V
Gate-source charge	Q _{gs} *	_	0.6	_	nC	V _{GS} = 4V
Gate-drain charge	Q _{gd} *	_	0.7	-	nC	I _D = 500mA

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	-	_	1.2	V	I _S = 500mA, V _{GS} =0V

*Pulsed

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